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Design of an Electro-Optic Bunch Length Monitor for the CERN-CTF3 probe beam

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Outline



Introduction for Califes



EOSD and Simulation



Schemes and comparison

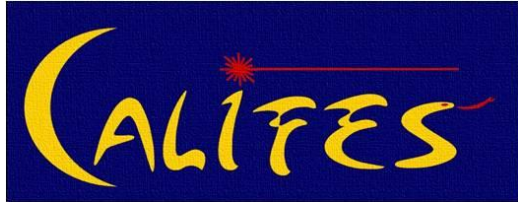


Resolution

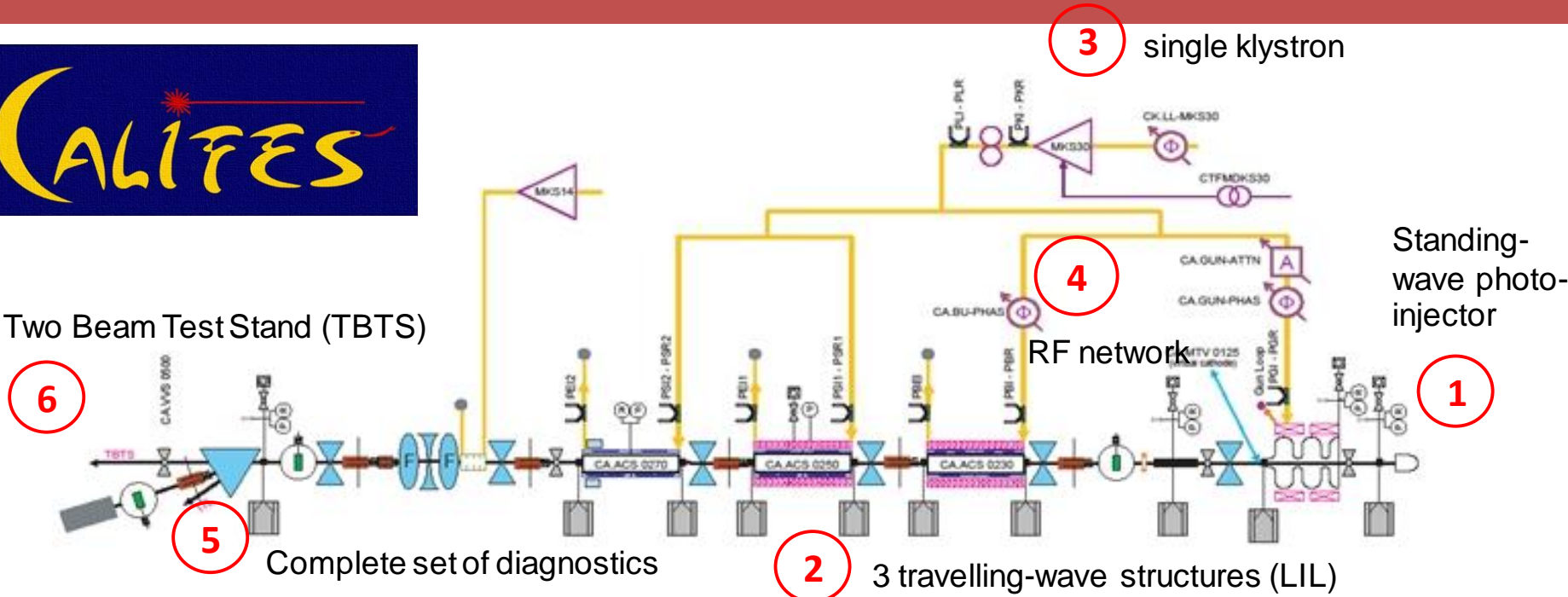


Summary and Outlook

Introduction ---- CALIFES in a nutshell



to Two Beam Test Stand (TBTS)



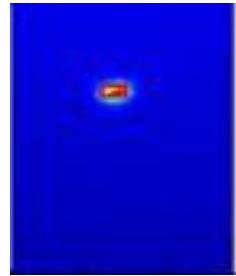
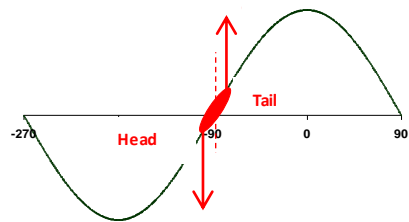
Energy	200 MeV
Energy spread	1% (FWHM)
Pulse length	0.6–150 ns
Bunch frequency	1.5 GHz
Bunch length	1.4 ps
Bunch charge	0.085–0.6 nC
Intensity	
- short pulse	1 A
- long pulse	0.13 A
Repetition rate	0.833 – 5 Hz

Existing bunch profile monitor:

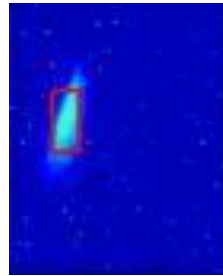
1. Deflecting cavity
2. Bunch length measurement with the 12 GHz high gradient acceleration structure

Existing bunch profile monitors

Deflecting cavity



Cavity OFF
 $\sigma_y = 0.24 \text{ mm}$

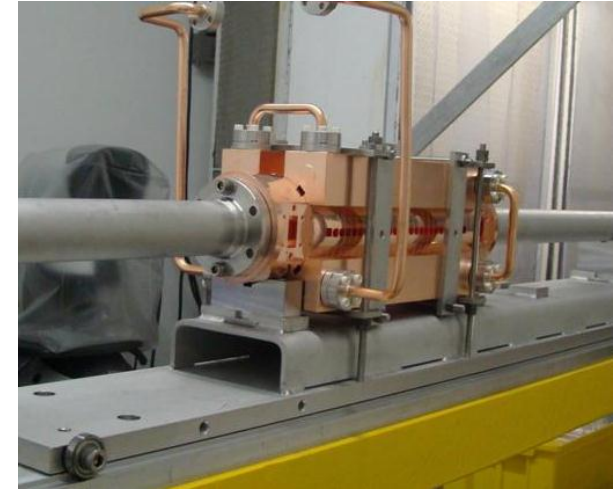


Cavity ON
 $\sigma_y = 1.47 \text{ mm}$

Operating principle:

- bunch pass at zero crossing in a deflecting cavity
- bunch head experiences a transverse kick downward, bunch tail upward
- bunch transverse size is then measured downstream on a beam profile monitor

12 GHz high gradient acceleration structure

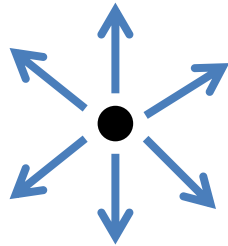


Operating principle:

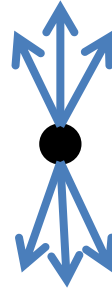
- bunch pass at zero crossing in the accelerating structure (12 GHz – 100 MV/m)
- bunch head is decelerated, bunch tail accelerated
- Energy spread is measured downstream in the spectrometer line
- Increase of energy spread is related to bunch length

Simulation: Coulomb field of e-bunch

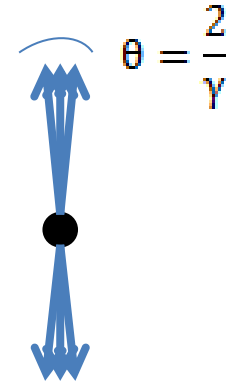
Coulomb field temporal profile



$\beta=0$



$\beta=0.9$



$\beta=0.9999$

$$E_{e0}(r_0, t) = \frac{e_0 \gamma}{4\pi \epsilon_0} \cdot \frac{r_0}{(r_0^2 + \gamma^2 v_e^2 (t - t_0)^2)^{3/2}}$$

Coulomb field of one electron

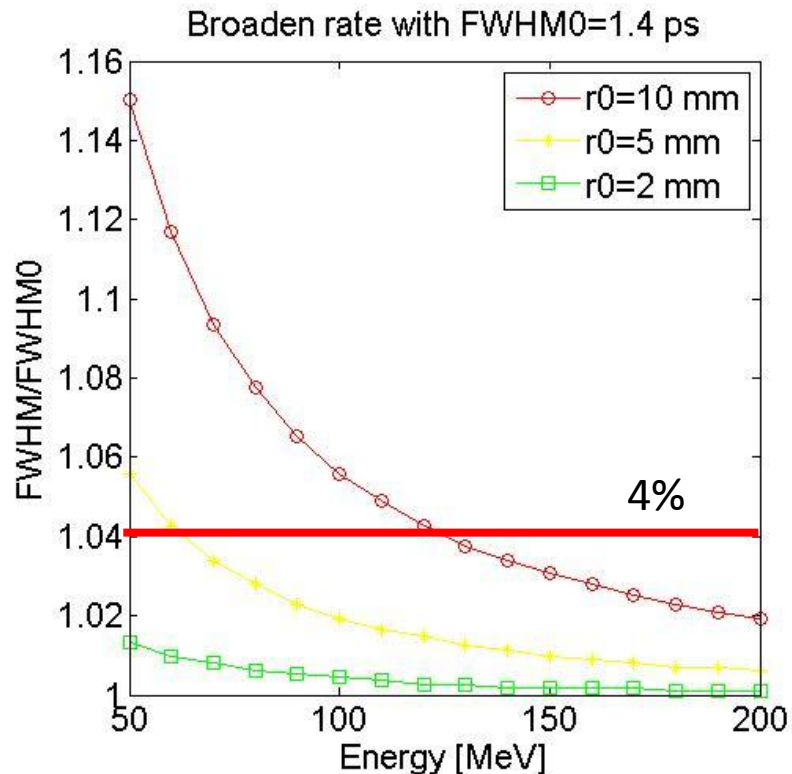
- High energy , Coulomb field temporal profile is approximately the bunch temporal profile
- Broadening of profile: $\Delta t \sim \frac{2r}{\gamma}$

Simulation: Coulomb field of e-bunch

Coulomb field temporal profile and broadening

$$E_{Colm} = E_{e0} * \rho$$

- Radial offset from single electron E_{e0}
- Electrons' density distribution within one bunch ρ
- Convolution

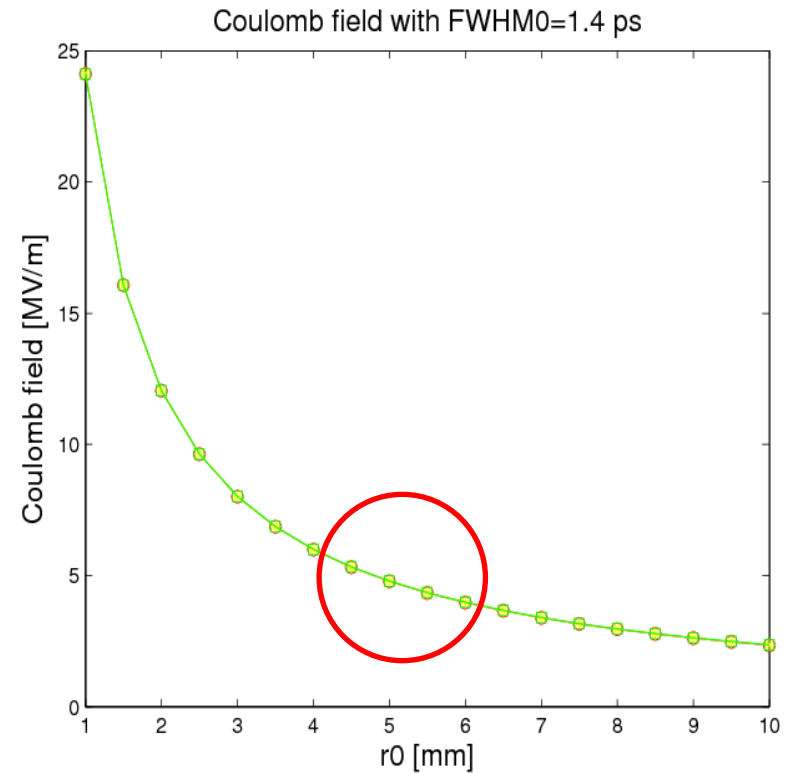
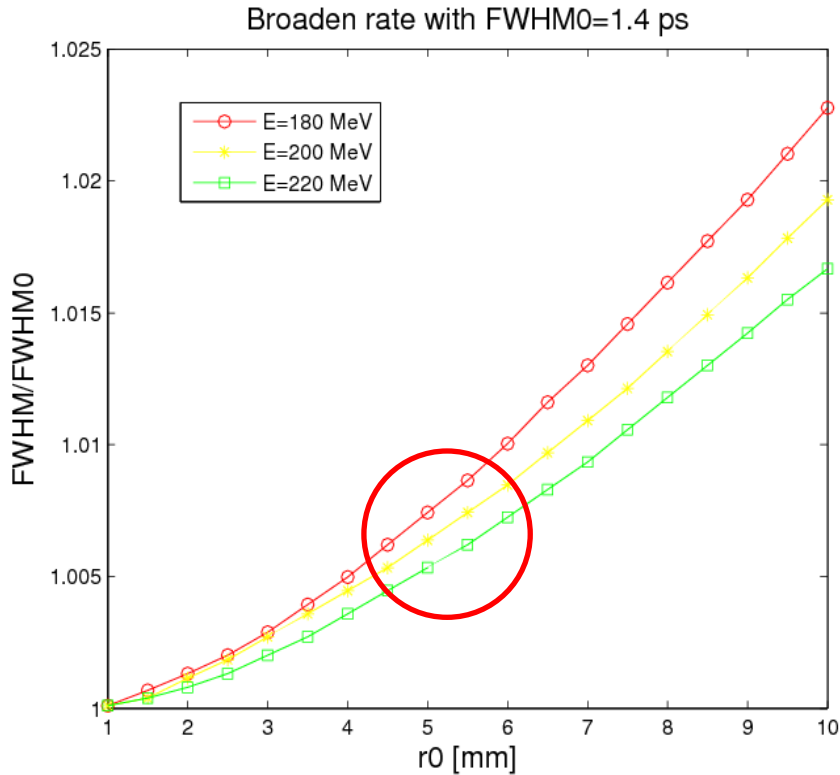


For high energy beam (>150 MeV):

Broadening rate < 4%

@ 10 mm

Simulation: Coulomb field of e-bunch



r0: the distance far away from e-bunch

Damage to crystal



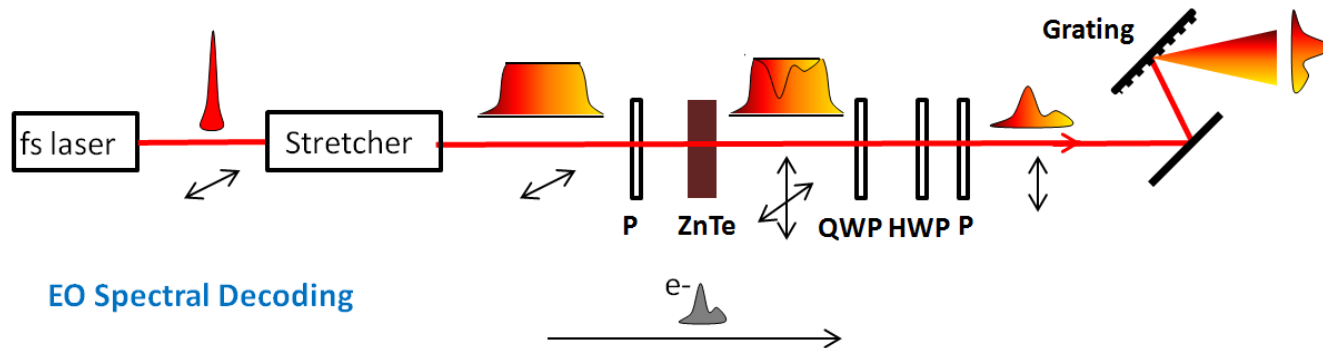
Crystal survives, low Coulomb field

Closer

Further

Simulation: EOSD

Electro-Optical Spectral Decoding:



- Linear chirped optical pulse
- Polarization variation caused by Coulomb field—laser nonlinear effect
- Polarization \rightarrow Intensity, by two crossed polarizers
- $I(\lambda) \leftrightarrow I(t)$

$$E_{out} = \begin{pmatrix} 0 & 1 \end{pmatrix} R(\varphi) M_{hw} R(-\varphi) R(\alpha) M_{qw} R(-\alpha) R(\theta) M_{EO} R(-\theta) \begin{pmatrix} E_{opt}^{chirp}(f) \\ 0 \end{pmatrix}$$

$R(\theta)$ ----- rotation matrix

M_{qw} ----- Jones matrix for quarter waveplate

M_{hw} ----- Jones matrix for half waveplate

Simulation: EOSD

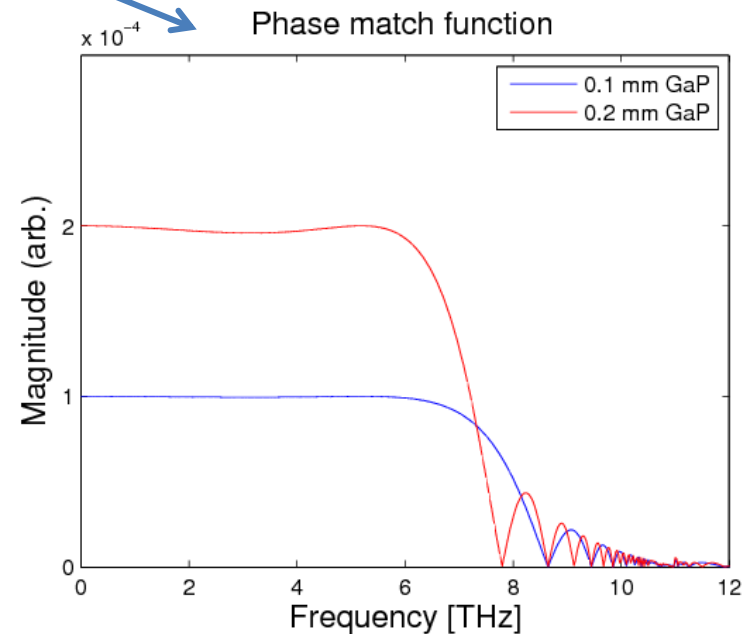
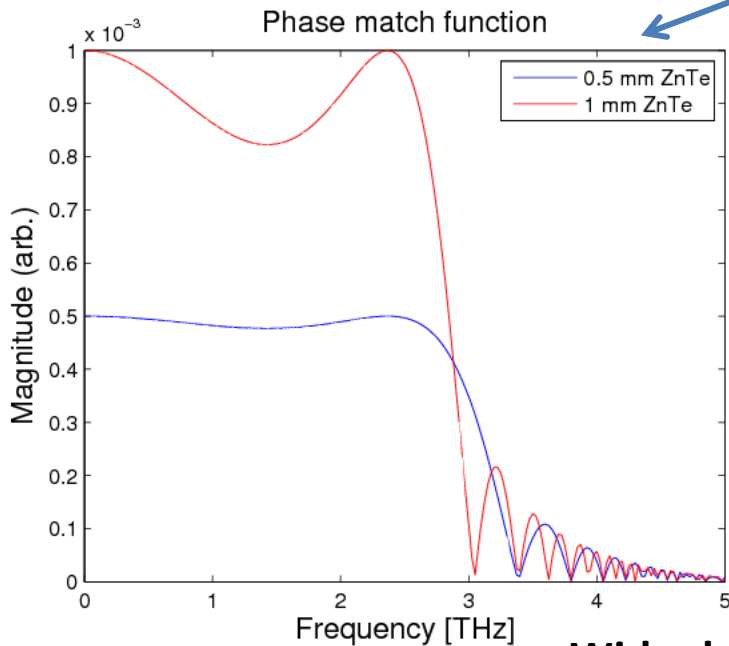
EO effect:

Frequency mixing

induce

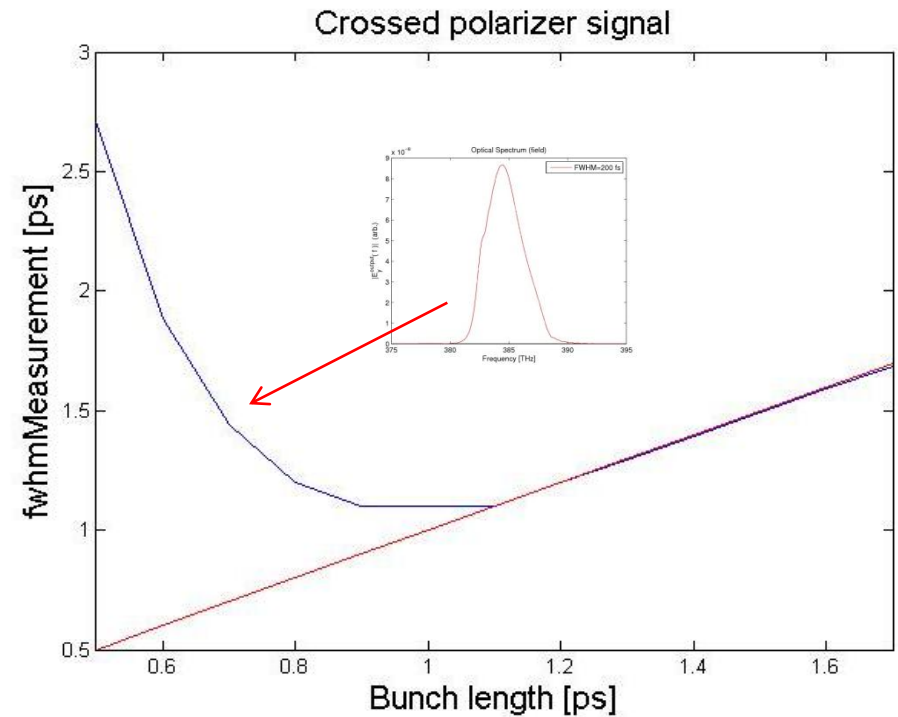
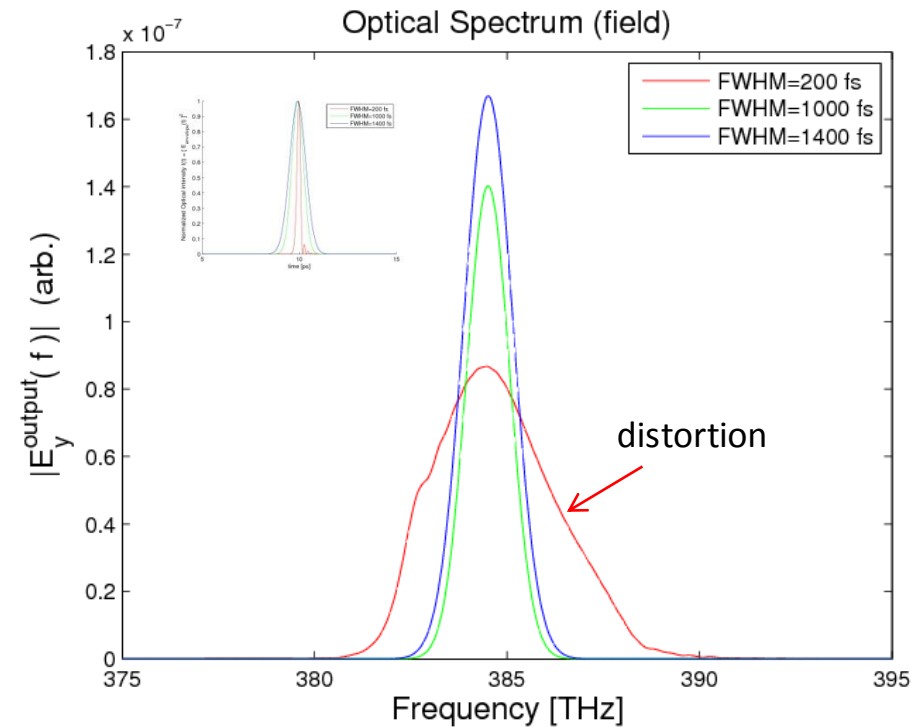
Polarization variation

$$\tilde{E}_{sum}(z, \omega) = \frac{i\omega^2}{2c^2 k_{opt}^R(\omega)} \exp [ik_{opt}(\omega)z] \times \int_{-\infty}^{+\infty} d\Omega \left\{ \chi_{eff}^{(2)}(\omega, \Omega) \left[\frac{\exp(i\Delta k(\omega, \Omega)z) - 1}{i\Delta k(\omega, \Omega)} \right] \times \tilde{E}_{THz}(0, \Omega) \tilde{E}_{opt}(0, \omega - \Omega) \right\}$$



Wider bandwidth, better resolution !

Simulation: EOSD results



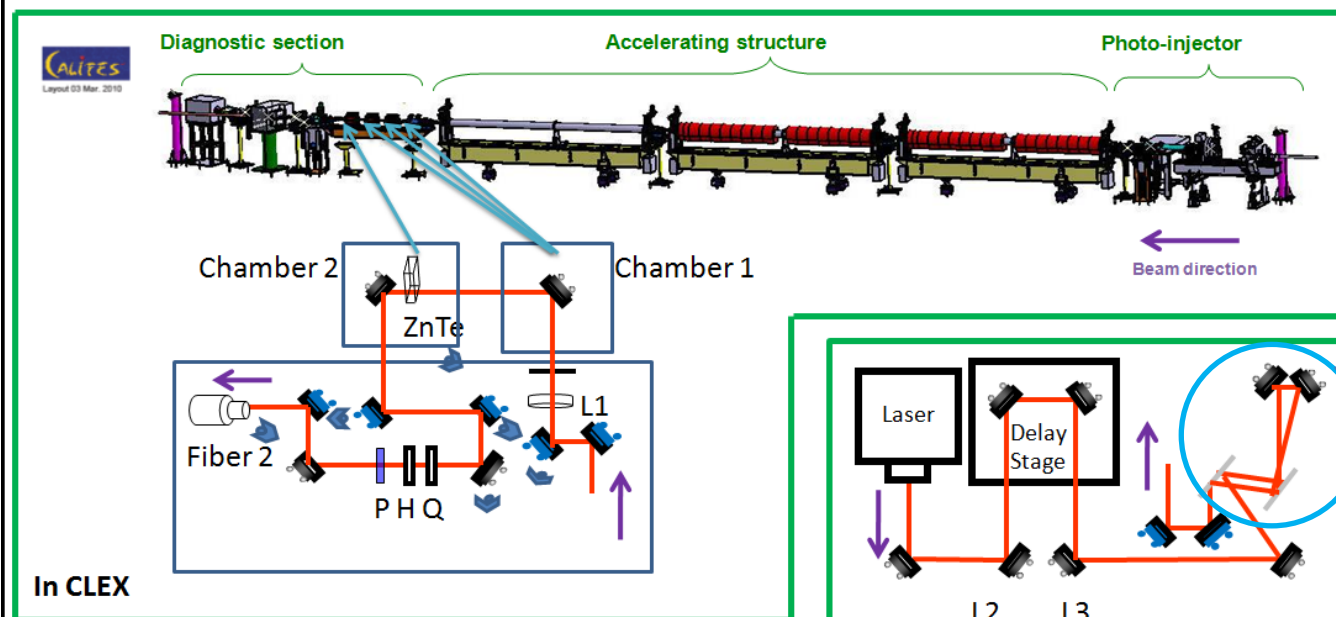
Distortion: bunch length < 1 ps

Other parameters:

Laser wavelength: 780nm Crystal thickness: 500 μ m
 Laser pulse energy: 1.5nJ Distance: 5mm
 Pulse duration: 150fs

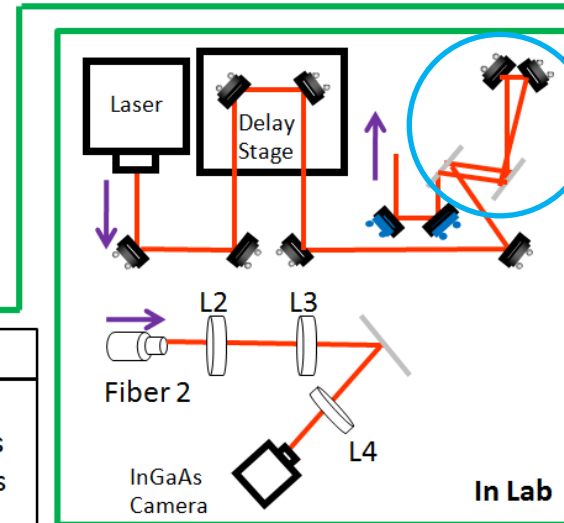
Short bunch----fast temporal modulation---- spectral content
---- $t \sim \lambda$ mapping

EO monitor Design for Califes



Stretcher:

- SF11 glass
- 100fs----3.24ps



Scheme

In CLEX		In Lab	
10 Motors	7 plane mirrors	1 Laser	10 plane mirrors
3 Rotate motors	2 polarizers	1 InGaAs Camera	3 gratings
6 Pinhole cameras	3 wave plates	1 motor stage	3 lens
	1 lens	4 Motors	1 fiber head
	1 fiber head		2 photodiodes
	2 photodiodes		

Simulation: EOSD results

Laser performance comparison

Laser	Wavelength (nm)	Pulse energy (nJ)	Crystal	Thickness (μm)	EO coefficient (pm/V)	Non-linear energy (pJ)
1	1030	10	GaP	200	0.97	0.118
2	780	1.8	ZnTe	1000	3.9	0.9
3	780	1.2	ZnTe	1000	3.9	0.6
4	780	2.7	ZnTe	1000	3.9	1.37



- Laser 1: Standard ytterbium fiber laser
- Laser 2: Standard erbium fiber laser
- Laser 3: Custom Er fiber laser with fiber transport
 - Normal fiber: higher energy, not stable
 - PM fiber: lower energy, stable
- Laser 4: Custom Er fiber laser with pulse picker
 - pulse energy can be changed

Assume :

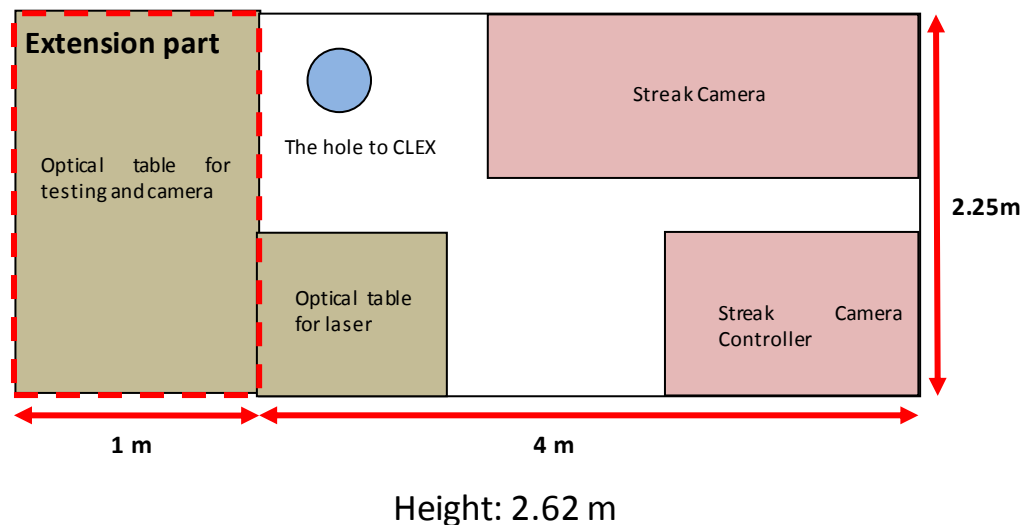
Bunch charge = 0.2 nC,
 $r_0 = 5 \text{ mm}$

EO monitor Design for Califes

Laser room safety

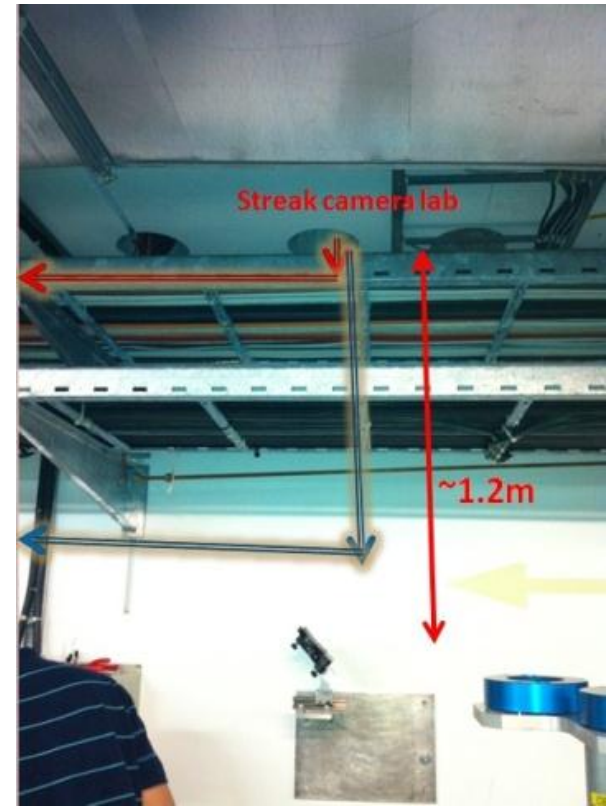
- An interlock shutter is needed for the laser room. When the door of the lab is opened, laser will be blocked automatically by the interlock shutter.
- When the laser is running, people in the lab should wear laser protection glasses.
- Signs (usually these are lights) should be both inside and outside of the lab to warn people that the laser is running.
- Follow the safety rules of laser room at CERN.

Laser room extension



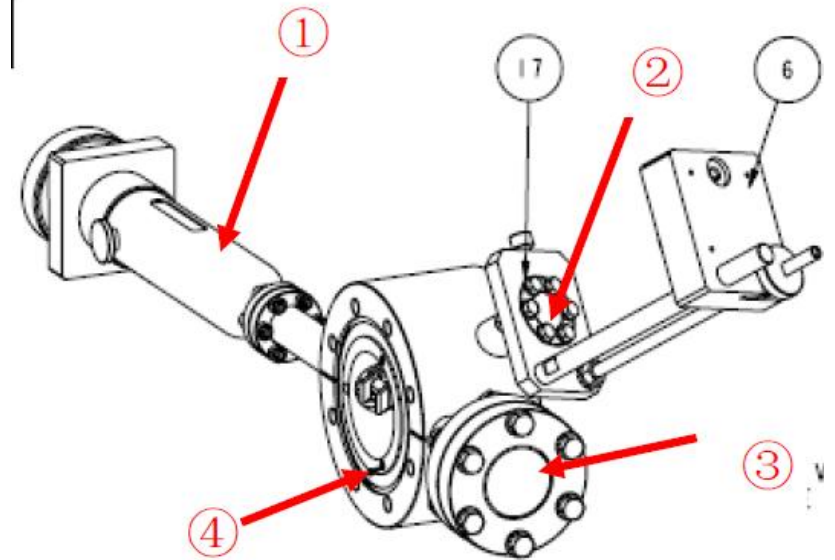
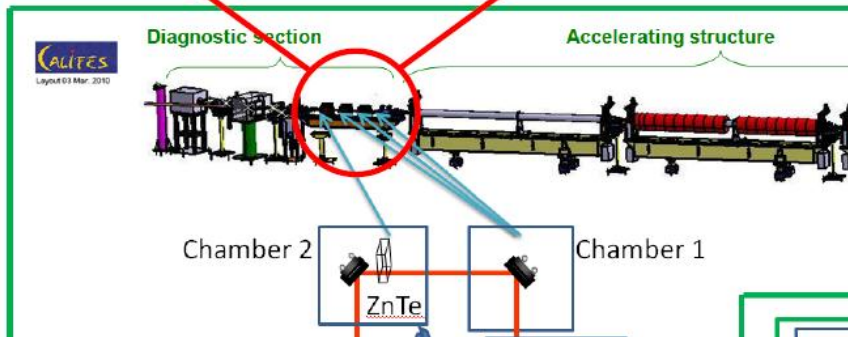
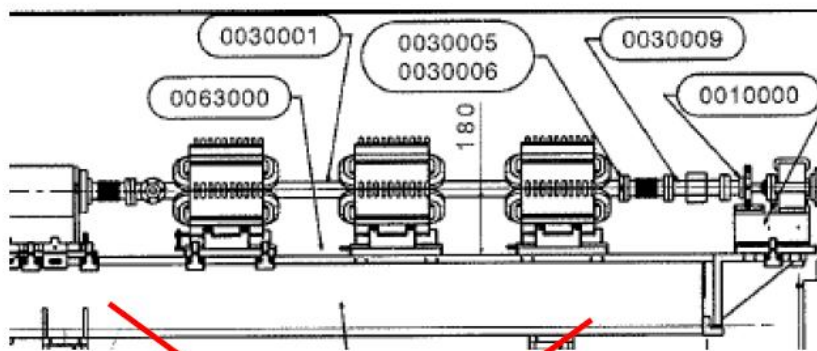
EO monitor Design for Califes

Laser Transport Line



EO monitor Design for Califes

Chamber design



- ① Adjustable arm
- ② Observation port
- ③ Laser input/output viewport
- ④ Central chamber

Operation and Commissioning

Laser

- Synchronization
- Timing : phase shifter and delay stage

Motors and Observers

- Controlled from the laser lab

Chambers

- Controlled in CTF3 control room

ICCD gated camera

- Controlled in laser lab
- Trigger signal: beam loss monitor around chamber

Expected Resolution

1. Distance between crystal and e-beam

$$\Delta t \sim \frac{2r}{\gamma} \sim 10 \text{ fs} \quad \text{at } r=5 \text{ mm}$$

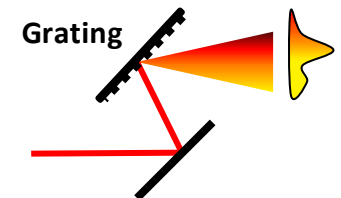
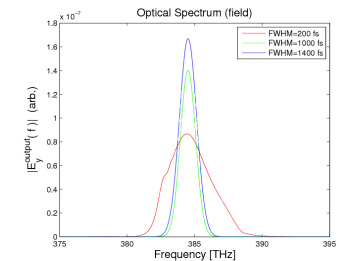
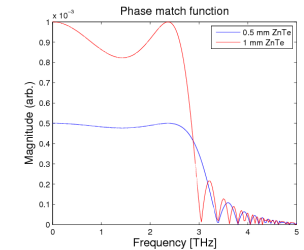
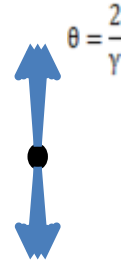
2. The frequency response of crystal (material and thickness)

for 1 mm ZnTe: $\sim 333 \text{ fs}$ $\sim 1/(3\text{THz})$

3. EOSD limitation (Laser pulse duration and chirped duration)




$$\tau_{\text{lim}} = \sqrt{\tau_0^{\text{FWHM}} \tau_c^{\text{FWHM}}} \sim 550 \text{ fs} \quad (100 \text{ fs} \rightarrow 3 \text{ ps})$$

4. Resolution of spectrometer and CCD $\sim 40 \text{ fs}$ (512 pixels)




Summary & Outlook

Summary:

-  EO system scheme and Laser room are prepared.
All the optical items are ordered.
-  Based on numerical simulation, the resolution of this system is expected to be sub-picosecond.
-  A EO bunch length measurement system will be installed at CTF3 in the summer of 2012.

Outlook:

-  Build up the optical system and continue to do experiments based on frequency up-conversion method and other new methods for resolution improvement.

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Thank You !

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